





Applications

- Communications
- Electronic Warfare
- Test Instrumentation
- EMC Amplifier



Product Features

Frequency Range: 2.5 to 6 GHz
P_{SAT}: 46.5 dBm @ P_{IN} = 26dBm, CW

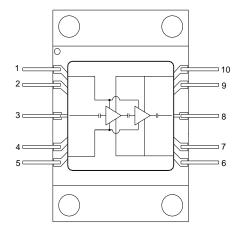
PAE: 36%

Small Signal Gain: 29 dB

• Bias: $V_D = 30 \text{ V}$, $I_{DQ} = 1.55 \text{ A}$, $V_G = -2.5 \text{ V}$ Typical

• Dimensions: 11.4 x 17.3 x 3.0 mm.

Functional Block Diagram



General Description

TriQuint's TGA2576-2-FL is a wideband power amplifier fabricated on TriQuint's proven 0.25um GaN on SiC production technology. Operating from 2.5 to 6 GHz, the TGA2576-2-FL achieves 40W of saturated output power, greater than 36% power-added efficiency and 29dB small signal gain.

For ideal thermal management and handling, the TGA2576-2-FL is offered in a CuW-based flanged packaged and can operate in both CW and pulsed modes.

Fully matched to 50Ω and with integrated DC blocking caps on both I/O ports, the TGA2576-2-FL is ideally suited to support a variety of commercial and defense related applications.

Lead-free and RoHS compliant

Evaluation Boards are available up on request.

Pin Configuration

| Pin No. | Symbol |
|------------|----------------|
| 1, 5 | V _G |
| 2, 4, 7, 9 | N/C |
| 3 | RF IN |
| 6, 10 | V _D |
| 8 | RF OUT |

Ordering Information

| Part | ECCN | Description |
|--------------|-------------|------------------------|
| TGA2576-2-FL | 3A001.b.2.a | 2.5 to 6GHz 40W GaN PA |

TGA2576-2-FL

2.5 to 6GHz 40W GaN Power Amplifier

Absolute Maximum Ratings

| Parameter | Value |
|---|--------------|
| Drain Voltage (V _D) | 40 V |
| Gate Voltage (V _G) | −5 to 0 V |
| Drain Current (I _D) | 5000 mA |
| Gate Current (I _G) | -18 to 35 mA |
| Power Dissipation (P _{DISS}) | 93 W |
| RF Input Power, CW, 50 Ω, T = 25°C | 28 dBm |
| Channel tremperature (T _{CH}) | 275°C |
| Mounting Temperature (30 Seconds) | 260°C |
| Storage Temperature | −40 to 150°C |

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

| Parameter | Value |
|--|---------|
| Drain Voltage (V _D) | 30 V |
| Drain Current (I _{DQ}) | 1550 mA |
| Drain Current Under RF Drive (I _{D_DRIVE}) | 4300 mA |
| Gate Voltage (V _G) | -2.5 V |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: 25° C, $V_D = 30$ V, $I_{DQ} = 1550$ mA, $V_G = -2.5$ V Typical, CW

| Parameter | Min | Typical | Max | Units |
|---|-----|---------------|-----|--------|
| Operational Frequency Range | 2.5 | | 6 | GHz |
| Small Signal Gain | | 29 | | dB |
| Output Power at Saturation (Pin = 26 dBm) | | 46.5 | | dBm |
| Power-Added Efficiency (Pin = 26 dBm) | | 36 (Mid-band) | | % |
| Gain Temperature Coefficient | | -0.02 | | dB/°C |
| Power Temperature Coefficient | | -0.02 | | dBm/°C |



Thermal and Reliability Information

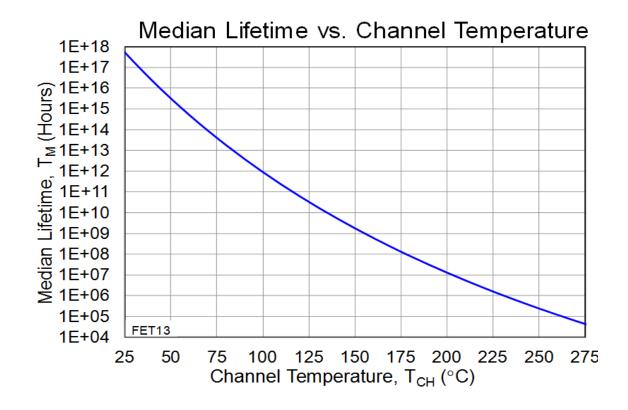
| Parameter | Test Conditions | Value | Units |
|---|---|-------------|-------|
| Thermal Resistance (θ _{JC}) ⁽¹⁾ | T _{BASE} = 85°C | 2.04 | °C/W |
| Channel Temperature Under RF Drive (T _{CH}) | $V_D = 30 \text{ V}, I_{D \text{ Drive}} = 3600 \text{ mA}, P_{OUT} = 100 \text{ mA}$ | 224 | °C |
| Median Lifetime Under RF Drive (T_M) | 46 dBm, P _{DISS} = 68 W | 1.69 x 10^6 | Hours |

Notes:

1. Measured from junction to center of package backside.

Median Lifetime

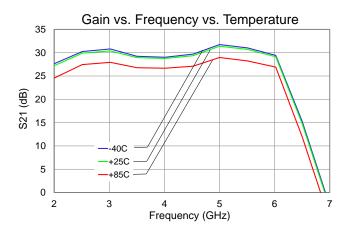
Test Conditions: $V_D = 40V$; Failure Criteria is 10% reduction in I_{D_MAX}

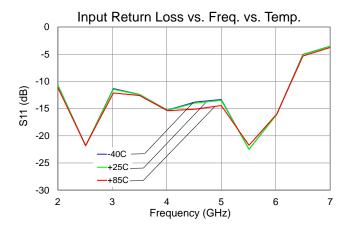


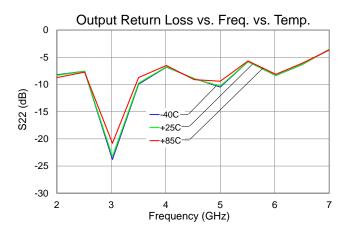


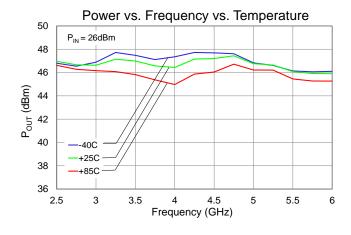
Typical Performance

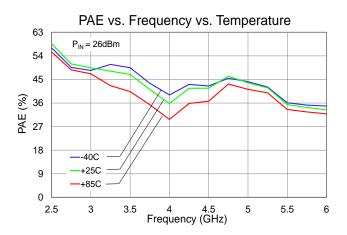
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW







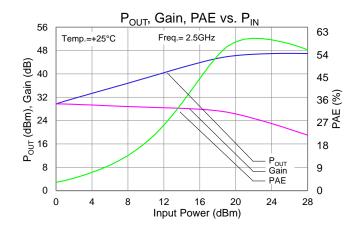


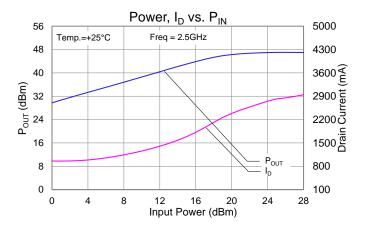


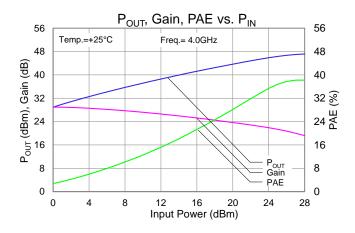


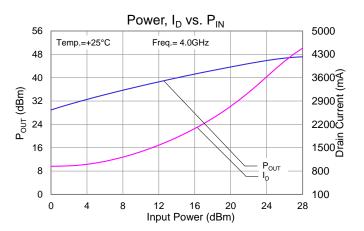
Typical Performance (con't.)

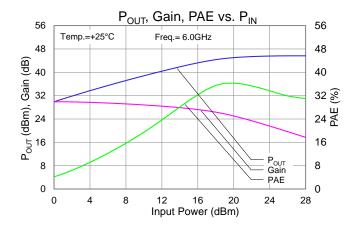
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW

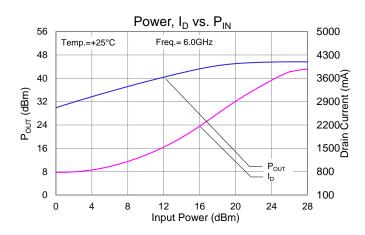








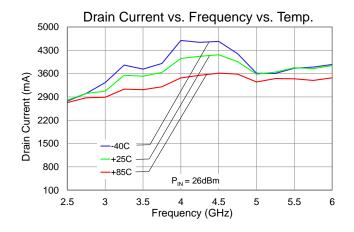


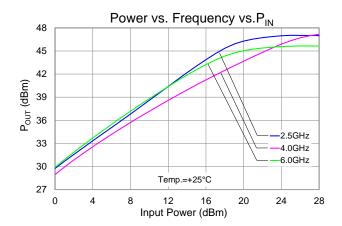




Typical Performance (con't.)

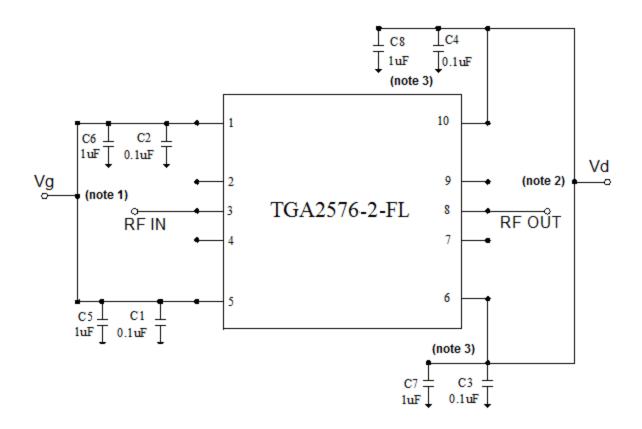
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW







Application Circuit



Notes:

- 1. V_G must be biased from both sides (Pins 1 and 5).
- 2. V_D must be biased from both sides (Pins 6 and 10).
- 3. Remove caps for pulsed drain operation.

Bias-up Procedure

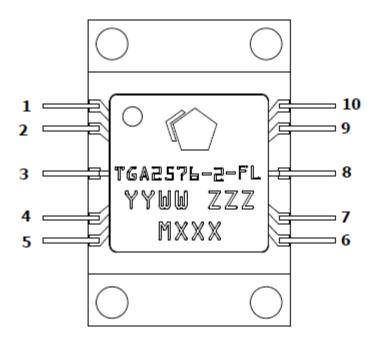
- 1. Set I_D to 4.5A, I_G to 20mA
- 2. V_G set to -5.0V.
- 3. V_D set to +30V.
- 4. Adjust V_G until I_{DQ} ~ 1550 mA (V_G ~ -2.5V Typical)
- 5. Turn on RF supply.

Bias-down Procedure

- 1. Turn off RF signal.
- 2. Reduce V_G to -5.0V. Ensure $I_{DQ} \sim 0$ mA.
- 3. Set V_D to 0V.
- 4. Set V_G to 0V.



Pin Description



| Pin | Symbol | Description |
|------------|----------------|--|
| 1, 5 | VG | Gate voltage. (1) |
| 2, 4, 7, 9 | N/C | No internal connection; may be grounded or left open on PCB. |
| 3 | RF IN | Input; matched to 50 Ω; DC blocked |
| 6, 10 | V _D | Bottom side Drain voltage. (2) |
| 8 | RF OUT | Output; matched to 50 Ω.; DC blocked. |
| | (Package Base) | RF and DC ground. |

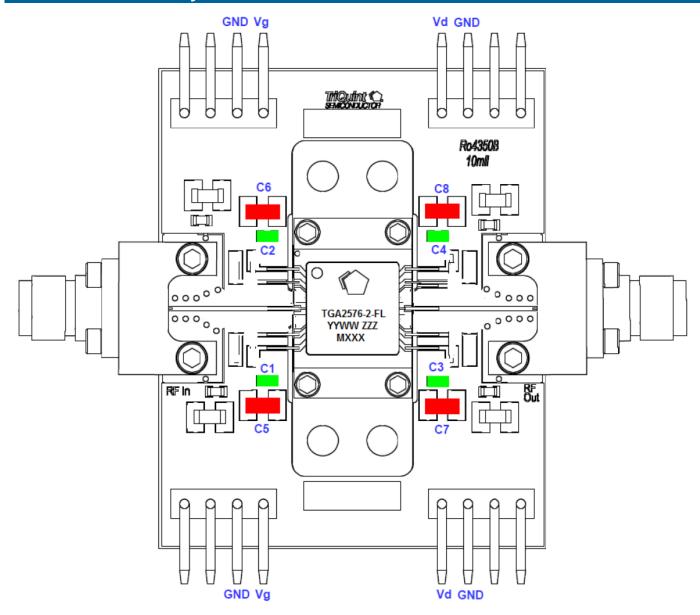
Notes:

- 1. Bias network is required; must be biased from both sides (Pins 1 and 5); see Application Circuit on page 7 as an example.
- 2. Bias network is required; must be biased from both sides (Pins 6 and 10); see Application Circuit on page 7 as an example.





Evaluation Board Layout



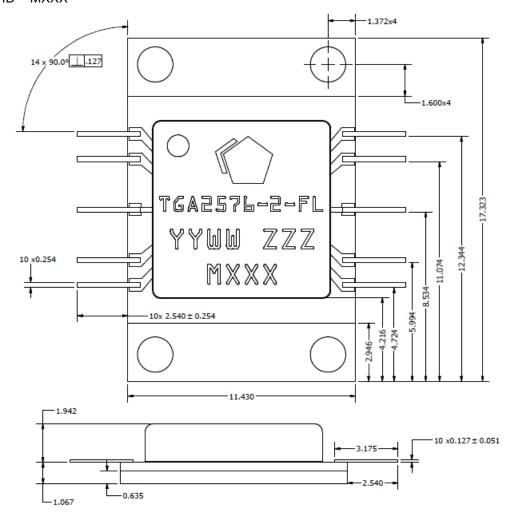
Bill of Material Reference Des. Value Description Mai

| Reference Des. | Value | Description | Manuf. | Part Number |
|----------------|--------|---------------------------|---------|-------------|
| C1 – C4 | 0.1 μF | Cap, 0603, 50 V, 10%, X7R | Various | |
| C5 – C8 | 1 μF | Cap, 1206, 50 V, 10%, X7R | Various | |



Mechanical Information – Package Information and Dimensions

Marking: Part number – TGA2576-2-FL Year/week/lot code - YYWW ZZZ Batch ID – MXXX



Notes:

- 1. Unless specified otherwise, dimensions are in millimeters (mm).
- 2. Unless specified otherwise, tolerances are \pm 0.127
- 3. Materials:

Package base: Copper Tungsten (CuW) composite
Package lid: LCD (liquid crystal polymer)
Package leads: Kovar, MIL I 23011C Class 1

Plating finish: Gold (Au) 1.27um minimum over Nickel (Ni) 2.54 to 8.89um

Assembly Notes

- 1. 0-80 screws are recommended for mounting the TGA2576-2-FL to the board.
- 2. To improve the thermal and RF performance, we recommend the following:
 - a) Apply thermal compound or 4 mils indium shim between the package and the board.
 - b) Attach a heat sink to the bottom of the board and apply thermal compound or 4 mils indium shim between the heat sink and the board.
- 3. Apply solder to each pin of the TGA2576-2-FL.





Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: Class 1B

Value: ≥500V and <1000V

Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

MSL Rating

Level 3 at +260 °C convection reflow The part is rated Moisture Sensitivity Level 3 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

ECCN

US Department of Commerce: 3A001.b.2.a

Solderability

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄0₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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